

Title (en)
LASER AMPLIFIER SYSTEM

Title (de)
LASERVERSTÄRKERSYSTEM

Title (fr)
SYSTÈME AMPLIFICATEUR LASER

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Application
EP 08760802 A 20080610

Priority

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Abstract (en)
[origin: WO2008152041A2] The invention relates to a laser amplifier system comprising a solid element thermally coupled to a heat sink that has a laser-active volume area in which at least one respective laser-active quantum structure made of semiconducting material is arranged on several parallel surfaces and in which the quantum structures are separated from one another by means of barrier structures, a pump radiation source that generates a pump radiation field, and an amplifier lens system that defines a laser amplifier radiation field. In order to improve said laser amplifier system in such a way that the quantum structures can be arranged in a less accurate manner, the quantum structures form at least one group, within which the barrier structures located between two of the quantum structures are designed as tunnel barrier structures and allow charge carriers to be tunneled between the quantum structures bordering said tunnel barrier structures.

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